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September 1983 Revised May 2005

MM74HC273 Octal D-Type Flip-Flops with Clear

General Description

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The MM74HC273 edge triggered flip-flops utilize advanced silicon-gate CMOS technology to implement D-type flipflops. They possess high noise immunity, low power, and speeds comparable to low power Schottky TTL circuits. This device contains 8 master-slave flip-flops with a common clock and common clear. Data on the D input having the specified setup and hold times is transferred to the Q output on the LOW-to-HIGH transition of the CLOCK input. The CLEAR input when LOW, sets all outputs to a low state.

Each output can drive 10 low power Schottky TTL equivalent loads. The MM74HC273 is functionally as well as pin compatible to the 74LS273. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical propagation delay: 18 ns
- Wide operating voltage range
- Low input current: 1 μA maximum
- Low quiescent current: 80 μA (74 Series)
- Output drive: 10 LS-TTL loads

Ordering Code:

Order Number	Package Number	Package Description
MM74HC273WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC273SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC273MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC273N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.



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Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions

(Note 2)	-
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to V _{CC} +1.5V
DC Output Voltage (V _{OUT})	–0.5 to V _{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	–65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (TL)	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V _{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those age to the device may occur.	values t	beyond whi	ch dam-

MM74HC273

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Paramotor	Conditions	Vee	TA =	$T_A = 25^{\circ}C$ $T_A = -40$ to $85^{\circ}C$ $T_A = -55$ to $125^{\circ}C$	Units		
Farameter	conditions	VCC	Тур		Guaranteed L	Units	
Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
Input Voltage		4.5V		3.15	3.15	3.15	V
		6.0V		4.2	4.2	4.2	V
Maximum LOW Level		2.0V		0.5	0.5	0.5	V
Input Voltage		4.5V		1.35	1.35	1.35	V
		6.0V		1.8	1.8	1.8	V
Minimum HIGH Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
		4.5V	4.5	4.4	4.4	4.4	V
		6.0V	6.0	5.9	5.9	5.9	V
	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
	$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
Maximum LOW Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	0	0.1	0.1	0.1	V
		4.5V	0	0.1	0.1	0.1	V
		6.0V	0	0.1	0.1	0.1	V
	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	$ I_{OUT} \le 4 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
	$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μA
Current							
Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		8	80	160	μA
Supply Current	$I_{OUT} = 0 \ \mu A$						
	Input Voltage Maximum LOW Level Input Voltage Minimum HIGH Level Output Voltage Maximum LOW Level Output Voltage Maximum Input Current Maximum Quiescent	$\begin{tabular}{ c c c c } \hline Minimum HIGH Level \\ Input Voltage \\ \hline \\ \hline \\ Maximum LOW Level \\ Input Voltage \\ \hline \\ \hline \\ \hline \\ Minimum HIGH Level \\ Output Voltage \\ \hline \\ $	$\begin{tabular}{ c c c c c } \hline Minimum HIGH Level \\ Input Voltage & 2.0V \\ Input Voltage & 4.5V \\ \hline 6.0V \\ \hline Maximum LOW Level \\ Input Voltage & 4.5V \\ \hline 10ut Voltage & V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 0utput Voltage & V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 10ut \le 20 \ \mu A & 2.0V \\ \hline 4.5V \\ \hline 6.0V \\ \hline V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 10ut \le 4.0 \ mA & 4.5V \\ \hline 10ut \le 5.2 \ mA & 6.0V \\ \hline Maximum LOW Level & V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 10ut \le 5.2 \ mA & 6.0V \\ \hline Maximum LOW Level & V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 0utput Voltage & V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 10ut \le 5.2 \ mA & 6.0V \\ \hline V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ \hline 10ut \le 5.2 \ mA & 6.0V \\ \hline Maximum Input & V_{IN} = V_{CC} \mbox{ or } GND & 6.0V \\ \hline Maximum Quiescent & V_{IN} = V_{CC} \mbox{ or } GND & 6.0V \\ \hline \end{tabular}$	$\begin{array}{ c c c c c } \hline Parameter & Conditions & V_{CC} & \hline Typ \\ \hline \hline \mbox{Minimum HIGH Level} \\ Input Voltage & 2.0V \\ Input Voltage & 4.5V \\ 6.0V & 6.0V \\ \hline \mbox{Maximum LOW Level} & 2.0V \\ Input Voltage & 4.5V \\ 6.0V & 6.0V \\ \hline \mbox{Minimum HIGH Level} & V_{IN} = V_{IH} \mbox{or } V_{IL} & \\ 0utput Voltage & I_{IOUT} \le 20 \ \mu A & 2.0V & 4.5V \\ 6.0V & 4.5V & 4.5 \\ 6.0V & 6.0 \\ \hline \mbox{Vin} = V_{IH} \mbox{or } V_{IL} & \\ I_{OUT} \le 20 \ \mu A & 4.5V & 4.2 \\ I_{OUT} \le 5.2 \ m A & 6.0V & 5.7 \\ \hline \mbox{Maximum LOW Level} & V_{IN} = V_{IH} \mbox{or } V_{IL} & \\ 0utput Voltage & I_{IOUT} \le 20 \ \mu A & 4.5V & 4.2 \\ \hline \mbox{IOUT} \le 5.2 \ m A & 6.0V & 5.7 \\ \hline \mbox{Maximum LOW Level} & V_{IN} = V_{IH} \mbox{or } V_{IL} & \\ 0utput Voltage & I_{IOUT} \le 20 \ \mu A & 2.0V & 0 \\ \hline \mbox{Vin} = V_{IH} \mbox{or } V_{IL} & \\ \hline \mbox{IOUT} \le 20 \ \mu A & 4.5V & 0.2 \\ \hline \mbox{Output Voltage} & V_{IN} = V_{IH} \mbox{or } V_{IL} & \\ \hline \mbox{IOUT} \le 5.2 \ m A & 6.0V & 0.2 \\ \hline \mbox{Maximum Input} & V_{IN} = V_{IH} \mbox{or } V_{IL} & \\ \hline \mbox{IOUT} \le 5.2 \ m A & 6.0V & 0.2 \\ \hline \mbox{Maximum Input} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Current} & V_{IN} = V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Quiescent} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Quiescent} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Quiescent} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Action Particle } & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Quiescent} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Action Particle } & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Quiescent} & V_{IN} = V_{CC} \mbox{or } GND & 6.0V \\ \hline \mbox{Maximum Action Particle } & V_{IN} = V_{CC} \mbox{Or } GND & 0.0 \\ \hline \mbox{Maximum Action Particle } & V_{IN} = V_{CC} \mbox{Maximum Action Particle } & V_{IN} \\ \hline \mbox{Maximum Action Particle } & V_{IN} = V_{ID} \mbox{Maximum Action Particle } & V_{ID} \mbox{Maximum Action Particle } & V_{ID} \mbox{Maximum Action Particle }$	$ \begin{array}{ c c c c c c } \hline Minimum HIGH Level \\ Input Voltage & 2.0V & 1.5 \\ Input Voltage & 4.5V & 3.15 \\ 6.0V & 4.2 \\ \hline Maximum LOW Level \\ Input Voltage & 2.0V & 0.5 \\ Input Voltage & 4.5V & 1.35 \\ 6.0V & 1.8 \\ \hline Minimum HIGH Level \\ Output Voltage & V_{IN} = V_{IH} \text{ or } V_{IL} \\ Output Voltage & V_{IN} = V_{IH} \text{ or } V_{IL} \\ \hline IlouTI \leq 20 \ \mu\text{A} & 2.0V & 2.0 & 1.9 \\ 4.5V & 4.5 & 4.4 \\ 6.0V & 6.0 & 5.9 \\ \hline V_{IN} = V_{IH} \text{ or } V_{IL} \\ \hline IlouTI \leq 5.2 \ m\text{A} & 6.0V & 5.7 & 5.48 \\ \hline Maximum LOW Level & V_{IN} = V_{IH} \text{ or } V_{IL} \\ \hline IlouTI \leq 5.2 \ m\text{A} & 6.0V & 0 & 0.1 \\ \hline 0.000000000000000000000000000000000$	$\begin{array}{ c c c c c } \hline Parameter & Conditions & V_{CC} & \hline Typ & Guaranteed L \\ \hline \hline$	Parameter Conditions V _{CC} Typ Guaranteed Limits Minimum HIGH Level 2.0V 1.5 1.5 1.5 1.5 Input Voltage 4.5V 3.15 3.15 3.15 3.15 Maximum LOW Level 2.0V 0.5 0.5 0.5 0.5 Input Voltage 2.0V 1.8 1.8 1.35 1.35 Minimum HIGH Level V _{IN} = V _{IH} or V _{IL} 0.0V 1.8 1.8 1.8 Minimum HIGH Level V _{IN} = V _{IH} or V _{IL} 0.0V 1.8 1.8 1.9 Output Voltage V _{IN} = V _{IH} or V _{IL} 0.0V 2.0V 2.0V 1.9 1.9 Minimum HIGH Level V _{IN} = V _{IH} or V _{IL} 0.0V 6.0V 6.0 5.9 5.9 Mupt Voltage V _{IN} = V _{IH} or V _{IL} 0.0V 6.0V 5.7 5.48 5.34 5.2 Maximum LOW Level V _{IN} = V _{IH} or V _{IL} 0.0V 0.0 0.1 0.1 0.1 Output Voltage V _{IN} = V _{IH} or V

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{O2}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

Symbo	, $T_A = 25^{\circ}C$, $C_L = 15 \text{ pF}$, t_r		Conditions			Тур	Guaranteed	Units	
f	Maximum Operating Fi	roquopov				50	Limit 30	MHz	
f _{MAX} Maximum Operating Frequency t _{PHL} , t _{PLH} Maximum Propagation						18	27	ns	
PHL, PLH	Delay, Clock to Output					10	21	The second	
t _{PHL}	Maximum Propagation					18	27	ns	
THE	Delay, Clear to Output								
t _{REM} Minimum Remova		ie,				10	20	ns	
	Clear to Clock								
ts	Minimum Setup Time					10	20	ns	
	Data to Clock								
t _H	Minimum Hold Time					-2	0	ns	
	Clock to Data								
t _W	Minimum Pulse Width					10	16	ns	
	Clock or Clear								
_	Example 2 Charace F , $t_r = t_f = 6$ ns (unless otherwise)								
Symbol	Parameter	Conditions	Vcc	$T_A = 25^{\circ}C$		$T_{A} = -40$ to 85°C	T _A = -55 to 125°	С	
Gymbol	i arameter	Conditions		Тур		Guaranteed	ed Limits		
f _{MAX}	Maximum Operating		2.0V	16	5	4	3		
	Frequency		4.5V	74	27	21	18		
			6.0V	78	31	24	20		
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	38	135	170	205		
	Delay, Clock to Output		4.5V	14	27	34	41		
	Maximum Decementian		6.0V	12	23	29	35		
t _{PHL}	Maximum Propagation		2.0V 4.5V	42 19	135 27	170 34	205 41		
	Delay, Clear to Output		4.3V 6.0V	19	27	29	35		
t _{REM}	Minimum Removal Time		2.0V	0	25	32	37	_	
REIN	Clear to Clock		4.5V	0	5	6	7		
			6.0V	0	4	5	6		
ts	Minimum Setup Time		2.0V	26	100	125	150		
	Data to Clock		4.5V	7	20	25	30		
			6.0V	5	17	21	25		
t _H	Minimum Hold Time		2.0V	-15	0	0	0		
	Clock to Data		4.5V	-6	0	0	0		
			6.0V	-4	0	0	0		
t _W	Minimum Pulse Width		2.0V	34	80	100	120		
	Clock or Clear		4.5V	11	16	20	24		
			6.0V	10	14	18	20		
t _r , t _f	Maximum Input Rise and		2.0V		1000	1000	1000		
	Fall Time, Clock		4.5V		500	500	500		
			6.0V		400	400	400		
t _{THL} , t _{TLH}	Maximum Output Rise		2.0V	28	75	95	110		
	and Fall Time		4.5V	11	15	19	22		
0	Dowor Dissingtion	(nor flin flor)	6.0V	9	13	16	19	+	
C _{PD}	Power Dissipation	(per flip-flop)		45					
	Capacitance (Note 5) Maximum Input								
C _{IN}				7	10	10	10		

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.









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